



# Performance Specifications NPO

## 參考資料

### Capacitance Test at 25 °C

Measured at 1 VRMS max. at 1 MHz ( 1 KHz for more than 1000 pF )

### Capacitance Tolerances

C = + - 0.25pF    D = + - 0.50pF    F = + - 1%  
G = + - 2%        J = + - 5%        K = + - 10%

### Operating Temperature Range

-55 °C to + 125 °C

### Temperature Coefficient

$\Delta C = 0 \pm 30 \text{ ppm/}^\circ\text{C}$

### Voltage Ratings

50 & 100 Vdc

### Dissipation Factor / Q Value

DF = 0.1% max. or Q :  $\geq 400 + 20C$  Less then 30 pF  
Q :  $\geq 1000$         30pF and over

### Insulation Resistance

100G or 1000ohmF minimum, whichever is less. The apply rated voltage for max.of 2 min. with 50 mA limiting current at 25 °C

### Dielectric Strength

250% of rated Vdc for 5s with charging current less than 50 mA

### Solderability

75% min. covered with smooth and bright solder coating under 230 + - 5 °C solder bath for 4 + - 1s dipping time

### Resistance to Leaching

20% of the metallization of the head face may be missing under 260 + - 5 °C solder bath for 30 + - 1.0s dipping time.

### Aging Rate

0% per decade hour

### Load Life

200% rated voltage at +125 °C for 1000hours, Measurement shall be taken after 24 hrs stabilization.

$\Delta C$  : < + - 3 % or + - 0.3pF whichever is less

Q :  $\geq 350$  for more than 30 pF

$\geq 275 + 2.5C$  for 30 pF > C > 10pF

$\geq 200 + 10C$  for less than 10 pF

IR :  $\geq 1\text{Gohm}$  or 50 ohmF whichever is less

### Humidity Test

500 hours at 40 + - 2 °C under 90 to 95% humidity. Measurement shall be taken after 24 hrs stabilization.

$\Delta C$  : < + - 5 % or + - 0.5pF whichever is less

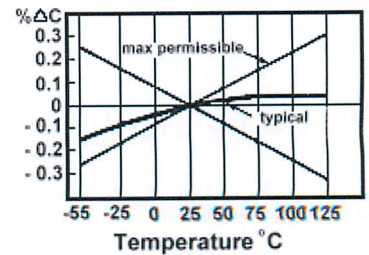
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Temperature Coefficient



D.F. vs. Temperature

